	Application No.	Applicant(s)	<u> </u>
Notice of Allowability	10/785,413	YAO ET AL.	
	Examiner	Art Unit	
	Hei Ve	4774	
	Hai Vo	1771	
The MAILING DATE of this communication apperature of the Mail Claims being allowable, PROSECUTION ON THE MERITS IS herewith (or previously mailed), a Notice of Allowance (PTOL-85) NOTICE OF ALLOWABILITY IS NOT A GRANT OF PATENT R of the Office or upon petition by the applicant. See 37 CFR 1.313	(OR REMAINS) CLOSED (or other appropriate comming or other appropriate comming or other application is separated or other application or other application is separated or other application or other applications.)	n this application. If not included	THIS initiative
1. A This communication is responsive to the amendment after	final filed 05/23/2007.		
2. The allowed claim(s) is/are 15 and 17-27.			
3. ☑ Acknowledgment is made of a claim for foreign priority una a) ☑ All b) ☐ Some* c) ☐ None of the: 1. ☐ Certified copies of the priority documents have 2. ☑ Certified copies of the priority documents have 3. ☐ Copies of the certified copies of the priority do International Bureau (PCT Rule 17.2(a)).	e been received. e been received in Applicati	on No. <i>09/</i> 539,929 .	ı the
* Certified copies not received:		•	
Applicant has THREE MONTHS FROM THE "MAILING DATE" noted below. Failure to timely comply will result in ABANDONN THIS THREE-MONTH PERIOD IS NOT EXTENDABLE.	of this communication to fil IENT of this application.	e a reply complying with the requiremen .	ıts
4. A SUBSTITUTE OATH OR DECLARATION must be subminFORMAL PATENT APPLICATION (PTO-152) which give	nitted. Note the attached EX es reason(s) why the oath o	AMINER'S AMENDMENT or NOTICE (or declaration is deficient.	DF
5. CORRECTED DRAWINGS (as "replacement sheets") mus	st be submitted.		
(a) ☐ including changes required by the Notice of Draftspers		w (PTO-948) attached	
1) 🔲 hereto or 2) 🔲 to Paper No./Mail Date		` ,	
(b) including changes required by the attached Examiner' Paper No./Mail Date	s Amendment / Comment o	r in the Office action of	
Identifying indicia such as the application number (see 37 CFR 1 each sheet. Replacement sheet(s) should be labeled as such in t	.84(c)) should be written on the header according to 37 C	the drawings in the front (not the back) of FR 1.121(d).	:
6. DEPOSIT OF and/or INFORMATION about the depo attached Examiner's comment regarding REQUIREMENT.	SIT OF BIOLOGICAL MAT FOR THE DEPOSIT OF BI	ERIAL must be submitted. Note the OLOGICAL MATERIAL.	
Attachment(s)			
1. Notice of References Cited (PTO-892)	5. Notice of Ir	formal Patent Application	
2. Notice of Draftperson's Patent Drawing Review (PTO-948)		ummary (PTO-413),	
3. Information Disclosure Statements (PTO/SB/08), Paper No./Mail Date		/Mail Date <u>20070530</u> . Amendment/Comment	
4. Examiner's Comment Regarding Requirement for Deposit	8. 🛭 Examiner's	Statement of Reasons for Allowance	
of Biological Material	9.		

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EXAMINER'S AMENDMENT

An examiner's amendment to the record appears below. Should the changes and/or additions be unacceptable to applicant, an amendment may be filed as provided by 37 CFR 1.312. To ensure consideration of such an amendment, it MUST be submitted no later than the payment of the issue fee.

Authorization for this examiner's amendment was given in a telephone interview with Gregory T. Lowen on 05/30/2007.

The application has been amended as follows:

The claims:

- 15. (currently amended) A porous insulating film consisting essentially of a highly heat resistant polyimide resin film having a fine porous structure wherein:
- a) fine continuous channels reaching to both surfaces of the insulating film in a nonlinear fashion have a mean pore size of $0.01 20.2 \, \mu m$ in the center of the film and $0.4 0.9 \, \mu m$ at both surfaces of the film and a porosity of 15 80%;
- b) the polyimide resin film is prepared from a polyimide precursor solution and consists essentially of a polyimide obtained from the combination of at least one tetracarboxylic acid component and a diamine component; and
 - c) the insulating film has
 - a thickness of 5 150 μ m,
 - a resistance to passage of air of from 30 sec/100 cc to 2000 sec/100 cc, and

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a heat shrinkage of not greater than about $\pm 1\%$ after being heat-treated at 105°C for 8 hours, and

does not contain a dense layer on either of the surfaces.

- 21. (currently amended) A porous insulating film consisting essentially of a highly heat resistant polyimide resin film having a fine porous structure wherein:
- a) fine continuous channels reaching to both surfaces of the insulating film in a nonlinear fashion have a mean pore size of 0.01 $\frac{20.2}{4}$ µm in the center of the film and 0.4 0.9 µm at both surfaces of the film; and
- b) the polyimide resin film is prepared from a polyimide precursor solution and consists essentially of a polyimide obtained from the combination of at least one tetracarboxylic acid component and a diamine component; and
 - c) the insulating film has
 - a thickness of 5 -100 μ m,
 - a resistance to passage of air of from 30 sec/100 cc to 2000 sec/100 cc,
 - a heat resistance temperature of at least 200°C, and
 - a heat shrinkage of not greater than $\pm 1\%$ after being heat-treated at 105°C

for 8 hours, and

does not contain a dense layer on either of the surfaces.

Cancel claim 16.

Reasons for Allowance

The following is an examiner's statement of reasons for allowance: Note that Applicants' amendment and Examiner's amendment are sufficient to overcome the 112

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claim rejections and the art rejections and sufficient to place the claims in condition for allowance.

Saunders teaches a polyimide film useful as a dielectric layer for semiconductor devices (abstract). Saunders teaches the porous film having a porosity of 68%, thickness of 22 microns, an average pore size ranging from 4.5 to 0.5 μ m, and a dielectric constant of 1.88. Saunders does not teach a porous film having a mean pore size of 0.01- 0.2 μ m in the center of the film and 0.4 - 0.9 μ m at both surfaces of the film. There is no motivation to combine Saunders with other references to achieve that feature.

Any comments considered necessary by applicant must be submitted no later than the payment of the issue fee and, to avoid processing delays, should preferably accompany the issue fee. Such submissions should be clearly labeled "Comments on Statement of Reasons for Allowance."

Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Hai Vo whose telephone number is (571) 272-1485. The examiner can normally be reached on Monday through Thursday, from 9:00 to 6:00.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Terrel Morris can be reached on (571) 272-1478. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

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Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for

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published applications may be obtained from either Private PAIR or Public PAIR.

Status information for unpublished applications is available through Private PAIR only.

For more information about the PAIR system, see http://pair-direct.uspto.gov. Should

you have questions on access to the Private PAIR system, contact the Electronic

Business Center (EBC) at 866-217-9197 (toll-free). If you would like assistance from a

USPTO Customer Service Representative or access to the automated information

system, call 800-786-9199 (IN USA OR CANADA) or 571-272-1000.

HV

Date: May 30, 2007

/Hai Vo/ Primary Examiner

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